



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

SCHOTTKY BARRIER DIODE

VOLTAGE 45 Volts CURRENT 0.1 Ampere

CH480KGP

APPLICATION

- * Low power rectification

FEATURE

- * Small surface mounting type. (SC-82/SOT-343)
- * Low IR. (IR=0.30uA Typ.)
- * This is a composite component and is ideal for reducing the number of components used.
- * High reliability

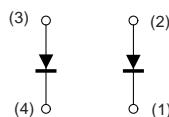
CONSTRUCTION

- * Silicon epitaxial planar

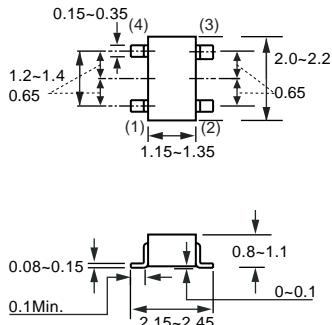
MARKING

- * 3T

CIRCUIT



SC-82/SOT-343



Dimensions in millimeters

SC-82/SOT-343

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CH480KGP	UNITS
Maximum Recurrent Peak Reverse Voltage	VR _{RM}	45	Volts
Maximum RMS Voltage	V _{RMS}	32	Volts
Maximum DC Blocking Voltage	V _D C	40	Volts
Maximum Average Forward Rectified Current	I _O	0.1	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	I _{FSM}	1.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	6.0	pF
Maximum Operating Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-40 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH480KGP	UNITS
Maximum Instantaneous Forward Voltage at I _F = 100mA	V _F	0.60	Volts
Maximum Average Reverse Current at V _R (1)= 10V	I _R (1)	1.0	uAmps
Maximum Average Reverse Current at V _R (2)= 40V	I _R (2)	5.0	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 10.0 volts.
2. ESD sensitive product handling required.

2002-5

RATING CHARACTERISTIC CURVES (CH480KGP)

FIG. 1 - FORWARD CHARACTERISTICS

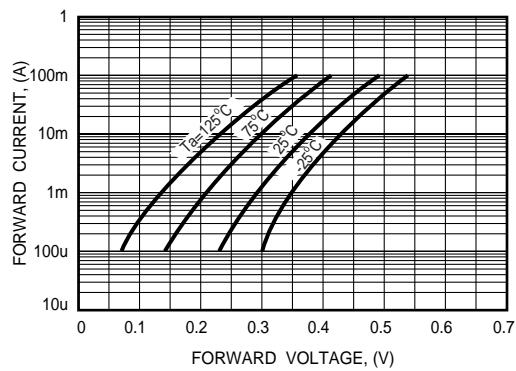


FIG. 2 - REVERSE CHARACTERISTICS

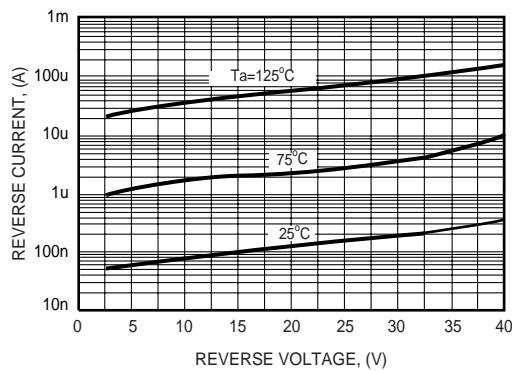


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

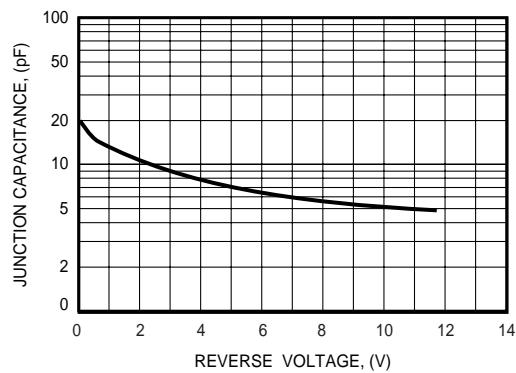


FIG. 4 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

